

## HiPerFRED<sup>2</sup>

**V<sub>RRM</sub>** = 2x 300 V  
**I<sub>FAV</sub>** = 30 A  
**t<sub>rr</sub>** = 35 ns

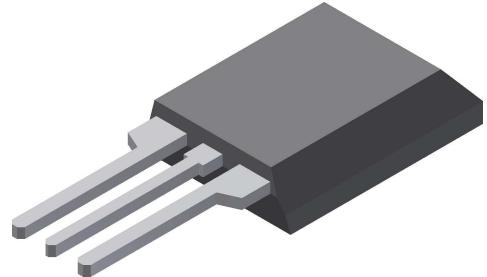
High Performance Fast Recovery Diode

Low Loss and Soft Recovery

Phase leg

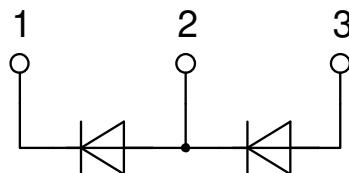
Part number

**DPG30P300PJ**



Backside: isolated

 E72873



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I<sub>rm</sub>-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I<sub>rm</sub> reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

### Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

### Package: ISOPLUS220

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

### Disclaimer Notice

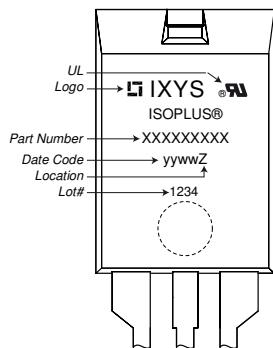
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**Fast Diode**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			300	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			300	V
$I_R$	reverse current, drain current	$V_R = 300 \text{ V}$ $V_R = 300 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1 0.2	$\mu\text{A}$ mA
$V_F$	forward voltage drop	$I_F = 30 \text{ A}$ $I_F = 60 \text{ A}$ $I_F = 30 \text{ A}$ $I_F = 60 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1.27 1.57 0.98 1.30	V V
$I_{FAV}$	average forward current	$T_C = 135^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 175^\circ\text{C}$		30	A
$V_{F0}$ $r_F$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 175^\circ\text{C}$		0.60 10.3	V $\text{m}\Omega$
$R_{thJC}$	thermal resistance junction to case				1.05	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.5		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ\text{C}$		145	W
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		450	A
$C_J$	junction capacitance	$V_R = 200 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	60		pF
$I_{RM}$	max. reverse recovery current		$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	3 8.5		A A
$t_{rr}$	reverse recovery time	$I_F = 30 \text{ A}; V_R = 200 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	35 65		ns ns

Package ISOPLUS220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			35	A
$T_{VJ}$	virtual junction temperature		-55		175	°C
$T_{op}$	operation temperature		-55		150	°C
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				2		g
$F_c$	mounting force with clip		20		60	N
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	1.0			mm
$d_{Spb/Apb}$		terminal to backside	3.0			mm
$V_{ISOL}$	isolation voltage	$t = 1 \text{ second}$ $t = 1 \text{ minute}$	50/60 Hz, RMS; $I_{ISOL} \leq 1 \text{ mA}$	3600 3000		V V

### Product Marking



### Part description

D = Diode  
P = HiPerFRED  
G = extreme fast  
30 = Current Rating [A]  
P = Phase leg  
300 = Reverse Voltage [V]  
PJ = ISOPLUS220AB (3)

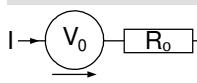
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPG30P300PJ	DPG30P300PJ	Tube	50	508134

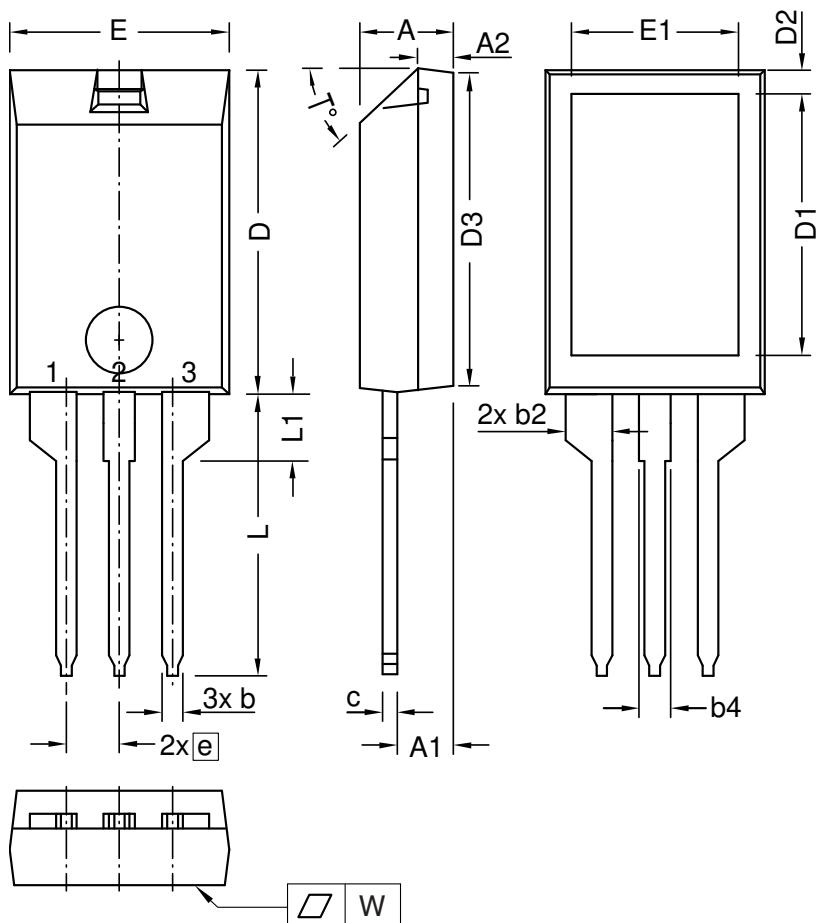
Similar Part	Package	Voltage class
DPG30P400PJ	ISOPLUS220 (3)	400

### Equivalent Circuits for Simulation

\* on die level

$T_{VJ} = 175^\circ\text{C}$

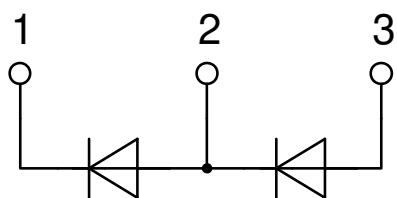
	<b>Fast Diode</b>	
$V_{0\ max}$	threshold voltage	0.6 V
$R_{0\ max}$	slope resistance *	7.1 mΩ

**Outlines ISOPLUS220**


Dim.	Millimeters		Inches	
	min	max	min	max
A	4.00	5.00	0.157	0.197
A1	2.50	3.00	0.098	0.118
A2	1.60	1.80	0.063	0.071
b	0.90	1.30	0.035	0.051
b2	2.35	2.55	0.093	0.100
b4	1.25	1.65	0.049	0.065
c	0.70	1.00	0.028	0.039
D	15.00	16.00	0.591	0.630
D1	12.00	13.00	0.472	0.512
D2	1.10	1.50	0.043	0.059
D3	14.90	15.50	0.587	0.610
E	10.00	11.00	0.394	0.433
E1	7.50	8.50	0.295	0.335
e	2.54	BSC	0.100	BSC
L	13.00	14.50	0.512	0.571
L1	3.00	3.50	0.118	0.138
T°	42.5	47.5		
W	-	0.1	-	0.004

Die konvexe Form des Substrates ist typ. < 0.04 mm über der Kunststoffoberfläche der Bauteilunterseite  
*The convex bow of substrate is typ. < 0.04 mm over plastic surface level of device bottom side*

Die Gehäuseabmessungen entsprechen dem Typ TO-273 gemäß JEDEC außer D und D1.  
*This drawing will meet all dimensions requirement of JEDEC outline TO-273 except D and D1.*



### Fast Diode

